DESCRIPTION

The AL1G07 Single buffer and driver is designed for 1.65V to 5.5V Vcc operation.

The AL1G07 is open drain and can be connected to other open-drain outputs to implement active-low wired-OR or active-high wired-AND functions. The AL1G07 is fully specified for partialpower- down applications using loff. The loff circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

The AL1G07 is available in Green SOT-25 and SC70-5 packages and operates over an ambient temperature range of -40°C to +125°C.

ORDERING INFORMATION

Package Type	Part Number			
SOT-25	E5	AL1G07E5R		
SPQ: 3,000pcs/Reel	ES	AL1G07E5VR		
SC70-5	C5	AL1G07C5R		
SPQ: 3,000pcs/Reel	C5	AL1G07C5VR		
Note	V: Halogen free Package			
Note	R: Tape & Reel			
AiT provides all RoHS products				

FUNCTIONAL BLOCK DIAGRAM



FEATURES

- Operating Voltage Range: 1.65V to 5.5V
- Low Power Consumption:1µA (Max)
- Operating Temperature Range:
 -40°C to +125°C
- Input and Open-Drain Output accept Voltage to 5.5V
- High Output Drive: ±24mA at Vcc=3.0V

APPLICATION

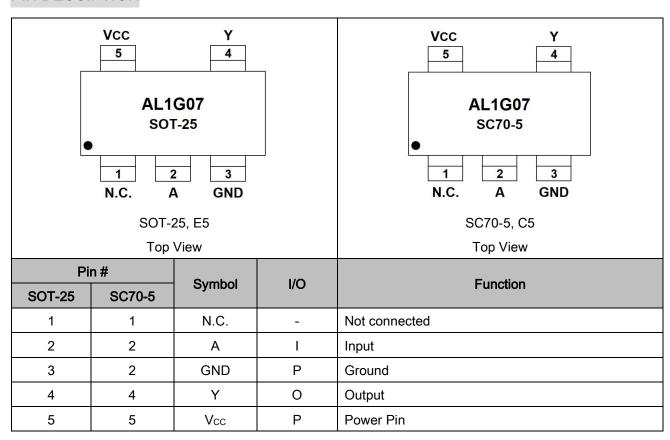
- AV Receiver
- Blu-ray Player and Home Theater
- DVD Recorder and Player
- Desktop or Notebook PC
- Digital Video Cameras (DVC)
- Embedded PC
- GPS: Personal Navigation Device
- Mobile Internet Device
- Network Projector Front End
- Portable Media Player
- Pro Audio Mixer
- Smoke Detector
- Solid State Drive (SSD): Enterprise
- High-Definition (HDTV)
- Table: Enterprise
- Audio Dock: Portable
- DLP Front Projection System
- DVR and DVS
- Digital Picture Frame (DPF)
- Digital Still Camera
- Personal Navigation Device (GPS)

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AL1G07

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PIN DESCIPTION



FUNCTION TABLE

Input	Output
Α	Y
L	L
Н	Z

H=High Voltage Level

L=Low Voltage Level

Z=High-impedance OFF-state

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ABSOLUTE MAXIMUM RATINGS

T_A = +25°C, unless otherwise noted. (1)

$I_A = +25^{\circ}C$, unless otherwise noted	. ⁽¹⁾	
Vcc, Supply Voltage Range	-0.5V ~ +6.5V	
V _I , Input Voltage Range (1)	-0.5V ~ +6.5V	
Vo, Voltage range applied to any o	-0.5V ~ +6.5V	
Vo, Voltage range applied to any o	utput in the high or low state (1)(2)	-0.5V ~ V _{CC} +0.5V
I _{IK} , Input Clamp Current	V ₁ <0	-50mA
lok, Output Clamp Current	Vo<0	-50mA
Io, Continuous Output Current		±50mA
Continuous Current Through Vcc of	or GND	±100mA
T _J , Junction Temperature		+150℃
T _{STG} , Storage Temperature		-65°C ~ +150°C
ESD Ratings		
V Floring that a Dischause	Human-Body Model (HBM)	±8000V
V _(ESD) , Electrostatic Discharge	Machine Model (MM)	±500V
Thermal Information		
D. Lastina to Assistant	SOT-25	273.8°C/W
ReJA, Junction-to-Ambient SC70-5		214.7°C/W
D. Josepher to Con-	SOT-25	126.8°C/W
R _{eJC(top)} ,Junction-to-Case	SC70-5	127.1°C/W
	•	

Stresses above may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated in the Electrical Characteristics are not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

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⁽¹⁾ The input and output negative-voltage ratings may be exceeded if the input and output current ratings are observed.

⁽²⁾ The value of V_{CC} is provided in the Recommended Operating Conditions table.

RECOMMENDED OPERATING CONDITIONS

At $T_A = +25$ °C, unless otherwise noted.

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit	
Cumply Maltage	\ /	Operating	1.65	-	5.5	\/	
Supply Voltage	Vcc	Data retention only	1.50	ı	-	V	
		V _{CC} =1.65V to 1.95V	0.65xVcc	ı	-		
High Lovel Input Voltage	\ \/	V _{CC} =2.3V to 2.7V	1.70	ı	-	17	
High-Level Input Voltage	ViH	V _{CC} =3V to 3.6V	2.20	ı	-	V	
		V _{CC} =4.5V to 5.5V	0.70xV _{CC}	ı	-		
	VIL	V _{CC} =1.65V to 1.95V	-	ı	$0.15xV_{CC}$		
Laur laural import vialtage		V _{CC} =2.3V to 2.7V	-	ı	0.30	V	
Low-level input voltage		V _{CC} =3V to 3.6V	-	ı	0.40		
		V _{CC} =4.5V to 5.5V	-	ı	$0.15xV_{CC}$		
Input Voltage	Vı		0	ı	5.5	V	
Output Voltage	Vo		0	ı	5.5	V	
Input transition rise or fall	Δt/Δν	V_{CC} =1.8V± 0.15V,2.5V ± 0.2V	-	ı	20		
		V _{CC} =3.3V± 0.3V	-	-	10	ns/V	
		V _{CC} =5V± 0.5V	-	-	5		
Operating Temperature	TA		-40	-	+125	°C	

AC ELECTRICAL CHARACTERISTICS

At $T_A = +25$ °C, unless otherwise noted.

Parameter	Symbol	Conditions		Min.	Тур.	Max.	Unit
		V _{CC} =1.8V±0.15V	C _L =30pF, R _L =1kΩ -40°C ~ +125°C	-	6.4	1	
Propagation Delay	t _{pd}	V _{CC} =2.5V±0.2V	C _L =30pF, R _L =500Ω -40°C ~ +125°C	-	4.5	-	ns
		V _{CC} =3.3V±0.3V	C _L =50pF, R _L =500Ω -40°C ~ +125°C	-	4.2	-	
		V _{CC} =5V±0.5V	$C_L=50pF, R_L=500\Omega$	-	3.7	-	
Input Capacitance	Ci	V _{CC} =3.3V	V _I =V _{CC} or GND	-	4.0	-	pF
		V _{CC} =1.8V		-	3.0	-	
Power Dissipation	C _{pd}	V _{CC} =2.5V	5_4 ONAL I—	-	3.0	-	
Capacitance		V _{CC} =3.3V	f=10MHz	-	4.0	-	pF
		V _{CC} =5V		-	6.0	-	

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DC ELECTRICAL CHARACTERISTICS

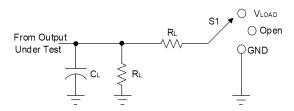
At $T_A = +25$ °C, unless otherwise noted.

	Parameter	Conditions		Min.	Тур.	Max.	Unit	
		$I_{OL} = 100 \mu A,$ $V_{CC} = 1.65 \text{V to } 5.5 \text{V}$		-	-	0.10		
		I _{OL} =4mA, V _{CC} =1.65V		-	-	0.45	V	
Vol		I _{OL} =8mA, V _{CC} =2.3V	-40°C ~ +125°C	-	-	0.30		
		I _{OL} =16mA, V _{CC} =3V		-	-	0.40		
		I _{OL} =24mA, V _{CC} =3V		-	-	0.55		
		I _{OL} =32mA, V _{CC} =4.5V		-	-	0.55		
	A input	V _I =5.5V or GND,	+25°C	-	±0.1	±1	T	
lı	A input	V _{CC} = 0V to 5.5V	-40°C ∼ +125°C	-	-	±5	μΑ	
		\/.or\/.=E E\/.\/=0\/.	+25°C	-	±0.1	±1		
l _{off}		V_1 or V_0 =5.5 V , V_{CC} =0 V	-40°C ~ +125°C	-		±10	μΑ	
Icc		V _I =5.5V or GND, I _O =0,	+25°C	-	0.1	1		
		V _{CC} =1.65V to 5.5V	-40°C ∼ +125°C	-	-	10	μΑ	
ΔΙα		One input at Vcc-						
		0.6V, Other inputs at	ner inputs at			F00		
Δicc		Vcc or GND	-40°C ~ +125°C	_	-	500	μA	
		V _{CC} =3V to 5.5V						

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DETAILED INFORMATION

Parameter Measurement Information



TEST	S1
t _{PZL} (see Notes E and F)	V_{LOAD}
t _{PLZ} (see Notes E and G)	V _{LOAD}
t _{PHZ} / t _{PZH}	V_{LOAD}

W	Inputs		V	W	•	Г	V
Vcc	Vı	t _r /t _f	V _M	VLOAD	CL	R∟	VΔ
1.8V±0.15V	Vcc	≤2ns	Vcc/2	2 x Vcc	30pF	1kΩ	0.15V
2.5V±0.2V	Vcc	≤2ns	V _{CC} /2	2 x V _{CC}	30pF	500Ω	0.15V
3.3V±0.3V	3V	≤2.5ns	1.5V	6V	50pF	500Ω	0.3V
5V±0.5V	Vcc	≤2.5ns	Vcc/2	2 x Vcc	50pF	500Ω	0.3V

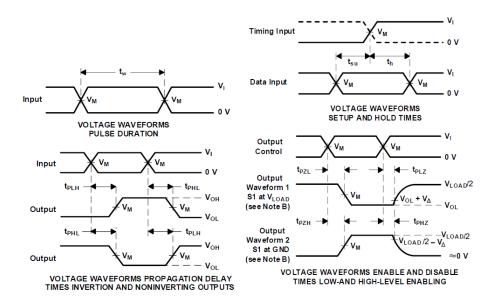


Figure 1. Load Circuit and Voltage Waveforms

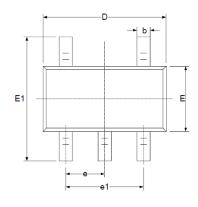
- (A) C_L includes probe and jig capacitance.
- (B) Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- (C) All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, Z_0 = 50 Ω .
- (D) The outputs are measured one at a time, with one transition per measurement.
- (E) Since this device has open-drain outputs, t_{PLZ} and t_{PZL} are the same as t_{pd} .
- (F) t_{PZL} is measured at V_M.
- (G) t_{PLZ} is measured at V_{OL} + V_{Δ} .
- (H) All parameters and waveforms are not applicable to all devices.

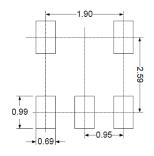
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AL1G07 LOGIC SINGLE BUFFER/DRIVER WITH OPEN-DRAIN OUTPUT

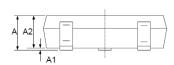
PACKAGE INFORMATION

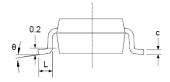
Dimension in SOT-25 (Unit: mm)





RECOMMENDED LAND PATTERN





Cymbol	Millim	neters		
Symbol	Min	Max		
А	1.050	1.250		
A1	0.000	0.100		
A2	1.050	1.150		
b	0.300	0.500		
С	0.100	0.200		
D	2.820	3.020		
E	1.500	1.700		
E1	2.650	2.950		
е	0.950 BSC			
e1	1.800	2.000		
L	0.300	0.600		
θ	0°	8°		

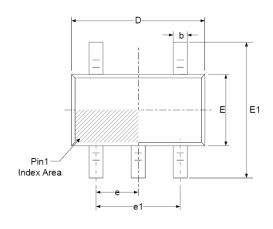
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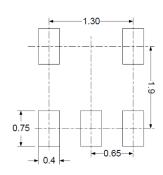
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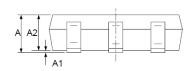
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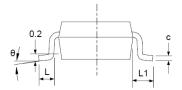
Dimension in SC70-5 (Unit: mm)





RECOMMENDED LAND PATTERN





Cymbol	Millim	neters		
Symbol	Min	Max		
А	0.900	1.100		
A1	0.000	0.100		
A2	0.900	1.000		
b	0.150	0.350		
С	0.080	0.150		
D	2.000	2.200		
E	1.150	1.350		
E1	2.150	2.450		
е	0.650	BSC		
e1	1.300 BSC			
L	0.260	0.460		
L1	0.525			
θ	0° 8°			

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